

# Current Transducer HTB 50 .. 400 - P and HTB 50 .. 100 - TP

For the electronic measurement of currents: DC, AC, pulsed..., with a galvanic isolation between the primary circuit (high power) and the secondary circuit (electronic circuit).







# **Electrical data**

curr	ry nominal rent rms <sub>PN</sub> (A)	Primary current measuring range I <sub>PM</sub> (A)	Туре		
± 50 ± 150		HTB 50-P, HTB 50			
± 100		± 300	HTB 100-P, HTB 1	00-TP <sup>1)</sup>	
± 150		± 450	HTB 150-P		
± 200		± 500	HTB 200-P		
± 3	300	± 600	HTB 300-P		
± 4	100	± 600	HTB 400-P		
$V_{\rm c}$	Supply volt	age (± 5 %) <sup>2)</sup>		± 1215	V
I <sub>C</sub>	Current cor	nsumption		± 15	mA
$V_{d}$	Rms voltag	e for AC isolation tes	t, 50 Hz, 1 min	2.5	kV
R <sub>IS</sub>	Isolation res	sistance @ 500 VDC		> 500	$M\Omega$
<b>V</b> <sub>OUT</sub>	Output volta	age (An <mark>alog</mark> )@ <mark>±</mark> I <sub>PN</sub> ,	$R_L = 10k\Omega$ , $T_A = 25^{\circ}C$	± 4	V
R <sub>OUT</sub>	Output inte	rnal re <mark>sis</mark> tance		100	Ω
R <sub>L</sub>	Load resista	ance		> 10	kΩ

# **Accuracy - Dynamic performance data**

X	Accuracy @ $I_{PN}$ , $T_A = 25^{\circ}$ C (excluding offset)	< ± 1	% of I <sub>PN</sub>
$\mathcal{E}_{\scriptscriptstyle L}$	Linearity error (0 ± I <sub>PN</sub> )	< ± 1	% of $I_{PN}$
$V_{OE}$	Electrical offset voltage @ T <sub>A</sub> = 25°C	$< \pm 30$	mV
<b>V</b> <sub>OH</sub>	Hysteresis offset voltage		
	after an excursion of 1 x $I_{PN}$	< ± 1	% of $I_{PN}$
TCV <sub>OE</sub>	Temperature coefficient of <b>V</b> <sub>OE</sub> HTB 50-(T)P	< ± 2.0	mV/K
	HTB 100-(T)P 400-P	< ± 1.0	mV/K
TCV	Temperature coefficient of <b>V</b> <sub>OUT</sub> (% of reading)	$< \pm 0.1$	%/K
t <sub>r</sub>	Response time to 90% of I <sub>PN</sub> step	< 3	μs
BW	Frequency bandwidth (- 3 dB) <sup>3)</sup>	DC 50	kHz

# **General data**

$\mathbf{T}_{A}$	Ambient operating temperature	- 40 + 80	°C
T <sub>s</sub>	Ambient storage temperature	- 40 + 85	°C
m	Mass	< 30 ( < 36)	g
	Standards	EN 50178 :	1997
	2 pins of Ø2mm diameter are available on transducer		
	for PCB soldering		

Notes: 1) -TP version is equipped with a primary bus bar.

- <sup>2)</sup> Operating at ±12V ≤ Vc < ±15V will reduce the measuring range.
- <sup>3)</sup> Derating is needed to avoid excessive core heating at high frequency.

# $I_{PN} = 50 .. 400 A$





### **Features**

- · Hall effect measuring principle
- Galvanic isolation between primary and secondary circuit
- Isolation voltage 2500 V
- Low power consumption
- Wide power supply: ± 12 ..15 V
- Primary bus bar option for 50
   A and 100 A version for ease of connection

# **Advantages**

- · Small size and space saving
- Only one design for wide current ratings range
- High immunity to external interference.

#### **Applications**

- AC variable speed drives
- Static converters for DC motor drives
- Battery supplied applications
- Uninterruptible Power Supplies (UPS)
- Switched Mode Power Supplies (SMPS)
- Power supplies for welding applications

# **Application domain**

Industrial



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#### **Isolation characteristics** Rms voltage for AC isolation test, 50 Hz, 1 min 2.5 kV Partial discharge extinction voltage rms @ 10pC > 500 Impulse withstand voltage 1.2/50 µs kV dCp Creepage distance > 4.5 mm dCI > 4.5 Clearance distance mm CTI Comparative tracking index (Group IIIa) 275

## **Application examples**

According to EN 50178 and CEI 61010-1 standards and following conditions :

- Over voltage category III
- Pollution degree 2
- Heterogeneous field

	EN 50178	IEC 61010-1
Single isolation	300 V	300 V
Reinforced isolation	150 V	150 V

#### Safety



This transducer must be used in electric/electronic equipment with respect to applicable standards and safety requirements in accordance with the manufacturer's operating instructions.



Caution, risk of electrical shock

When operating the transducer, certain parts of the module can carry hazardous voltage (eg. primary busbar, power supply).

Ignoring this warning can lead to injury and/or cause serious damage.

This transducer is a built-in device, whose conducting parts must be inaccessible after installation.

A protective housing or additional shield could be used.

Main supply must be able to be disconnected.



# **Dimensions HTB 50 .. 400-P and HTB 50 .. 100-TP** (in mm. 1 mm = 0.0394 inch)

